Thyristor Semiconductor Device - Page 1 of 1



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# Inclosure Material:

Metal

**Overall Length:** 

Between 0.330 inches and 0.505 inches

# **Overall Height:**

0.535 inches

# **Mounting Facility Quantity:**

1

#### **Mounting Method:**

Threaded stud

#### **Overall Width Across Flats:**

0.559 inches

#### Thread Size:

0.250 inches

#### Semiconductor Material:

Silicon

#### Voltage Rating In Volts Per Characteristic:

400.0 breakover voltage, dc

#### **Current Rating Per Characteristic:**

16.00 amperes source cutoff current of standard range

# Power Rating Per Characteristic:

500.0 milliwatts small-signal input power, common-collector preset

# Maximum Operating Tempurature Per Measurement Point:

100.0 degrees celsius junction

# **Special Features:**

Junction pattern arrangement: pnpn

# **Thread Series Designator:**

Unf

# **Terminal Type And Quantity:**

3 insulated wire lead

Shelf Life:

N/a

#### Unit Of Measure:

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# Demilitarization:

No

# Fiig:

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